



A Product Line of **Diodes Incorporated**

ZXTN19020DG

20V NPN HIGH GAIN TRANSISTOR IN SOT223

Features

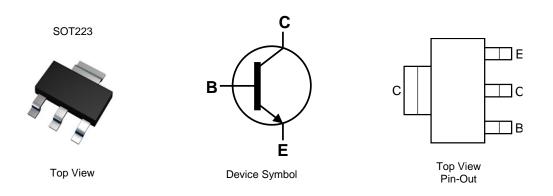
- $BV_{CEX} > 70V$
- $BV_{CEO} > 20V$
- $BV_{ECO} > 4.5V$
- I_C = 9A High Continuous Current
- Low Saturation Voltage V_{CE(sat)} < 35mV @ 1A
- $R_{CE(sat)} = 20m\Omega$
- Complementary PNP Type: ZXTP19020DG
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

Applications

- **PSU Start-Up Circuit**
- **DC-DC Converters**
- Motor Drive
- Relay, Lamp and Solenoid Drive



Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN19020DGTA	AEC-Q101	ZXTN19020D	7	12	1,000
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

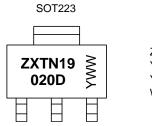
. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



ZXTN19020D = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)





ZXTN19020DG

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	70	V
Collector-Emitter Voltage (forward blocking)	V _{CEX}	70	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Collector Voltage (reverse blocking)	V _{ECX}	6	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	lc	9	A
Base Current	IB	1	A
Peak Pulse Current	I _{CM}	20	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1.2 9.6		
Power Dissipation	(Note 6)		1.6 12.8	W	
Linear Derating Factor	(Note 7)	- P _D	3 24	mW/°C	
	(Note 8)		5.3 42		
	(Note 5)		104		
Thermal Desistance Junction to Ambient	(Note 6)	D	78		
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	42	°C/W	
	(Note 8)		23.5		
Thermal Resistance, Junction to Lead (Note 9)		R _{θJL}	16		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

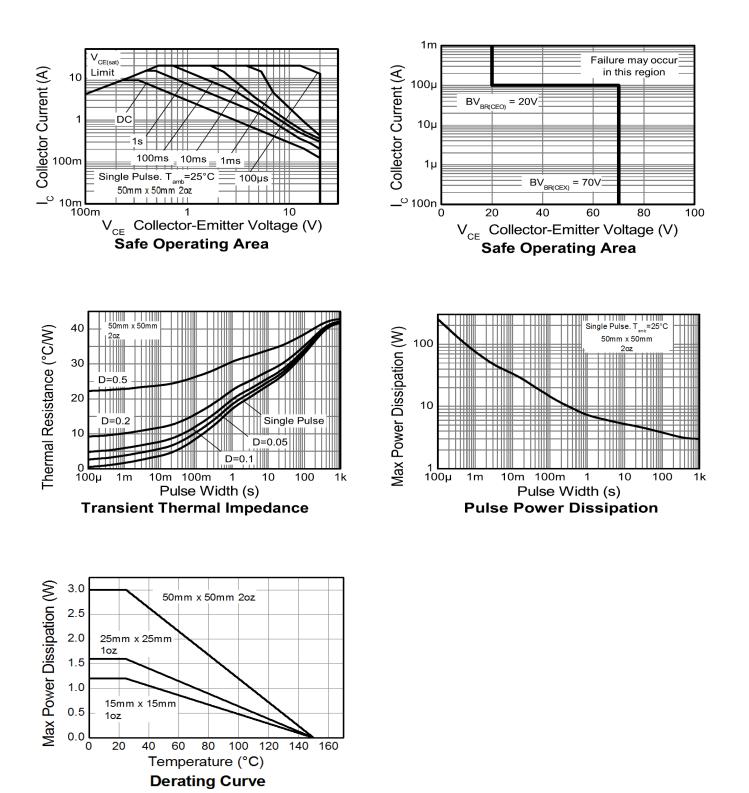
5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in steady-state. 6. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

Same as Note 6, except the device is mounted on 25mm 225mm 102 copper.
Same as Note 6, except the device is mounted on 50mm x 50mm 202 copper.
Same as Note 8 measured at 1<5 seconds.
Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information (@T_A = +25°C, unless otherwise specified.)





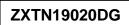


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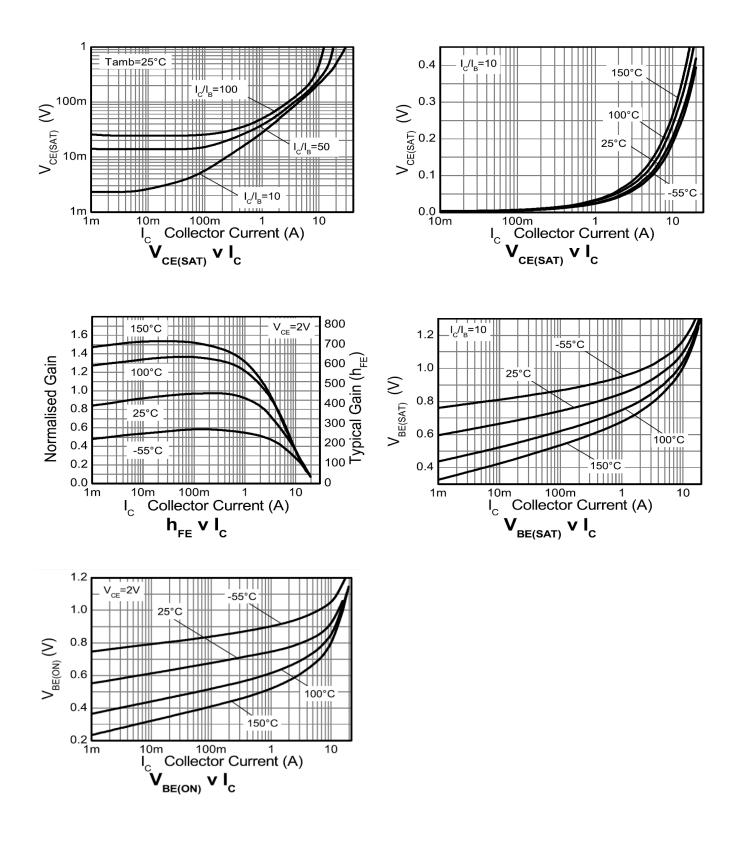
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	70	100	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (forward blocking)	BV _{CEX}	70	100	-	V	$I_C = 100\mu A$, $R_{BE} < 1k\Omega$ or -1V< $V_{BE} > 0.25V$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	20	30	-	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Collector Breakdown Voltage (reverse blocking)	BV _{ECX}	6	8.4	-	V	$I_{C} = 100 \mu A$, $R_{BC} < 1 k \Omega or$ 0.25V< $V_{BC} > -0.25V$
Emitter-Collector Breakdown Voltage (reverse blocking)	BV _{ECO}	4.5	5.7	-	V	I _E = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.4	-	V	I _E = 100μA
Collector Cut-Off Current		-	< 1	50	nA	V _{CB} = 70V
	I _{CBO}	_		0.5	μA	$V_{CB} = 70V, T_A = +100^{\circ}C$
Collector-Emitter Cut-Off Current	I _{CEX}	-	_	100	nA	V_{CE} = 70V, R_{BE} <1k Ω or -1V < V_{BE} > 0.25V
Emitter Cut-Off Current	I _{EBO}	-	< 1	50	nA	$V_{EB} = 5.6V$
	V _{CE(sat)}	-	27	35	mV	$I_{C} = 1A, I_{B} = 100mA$
		-	50	70	mV	$I_{C} = 1A, I_{B} = 10mA$
Collector-Emitter Saturation Voltage (Note 11)		-	80	100	mV	$I_{\rm C} = 2A, I_{\rm B} = 20mA$
		-	63	80	mV	$I_{C} = 2A, I_{B} = 40mA$
		-	85	110	mV	$I_{C} = 4A, I_{B} = 400mA$
		-	200	250	mV	$I_{C} = 9A, I_{B} = 450mA$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	-	1040	1150	mV	$I_{C} = 9A, I_{B} = 450mA$
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	-	910	1050	mV	$I_{C} = 9A, V_{CE} = 2V$
		300	450	900	-	$I_{C} = 100 \text{mA}, V_{CE} = 2 \text{V}$
		260	390	-	-	$I_{C} = 2A, V_{CE} = 2V$
DC Current Gain (Note 11)	h _{FE}	130	175	-	-	$I_{C} = 9A, V_{CE} = 2V$
		50	75	-	-	$I_{C} = 15A, V_{CE} = 2V$
		-	30	-	-	$I_{C} = 20A, V_{CE} = 2V$
Current Gain-Bandwidth Product (Note 11)	f _T	-	160	-	MHz	$V_{CE} = 10V$, $I_C = 50mA$, f = 100MHz
Input Capacitance (Note 11)	Cibo	-	297	400	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance (Note 11)	Cobo	-	32.6	40	pF	$V_{CB} = 10V$, f = 1MHz
Delay Time	t _d	-	129	-	ns	
Rise Time	tr	-	96	-	ns	$I_{C} = 1A, V_{CC} = 10V,$
Storage Time	ts	-	398	– ns I _{B1} = -		$I_{B1} = -I_{B2} = 10mA$
Fall Time	tf	_	90	_	ns	

Note: 11. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

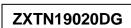




Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

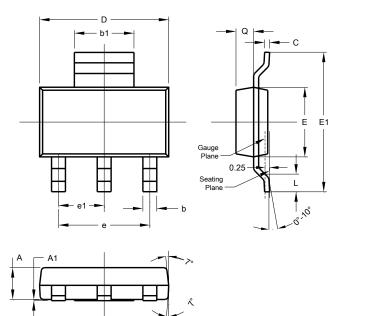






Package Outline Dimensions

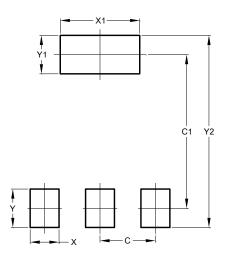
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	501	-222				
SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
ш	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00





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